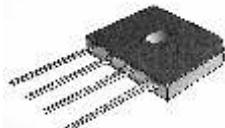




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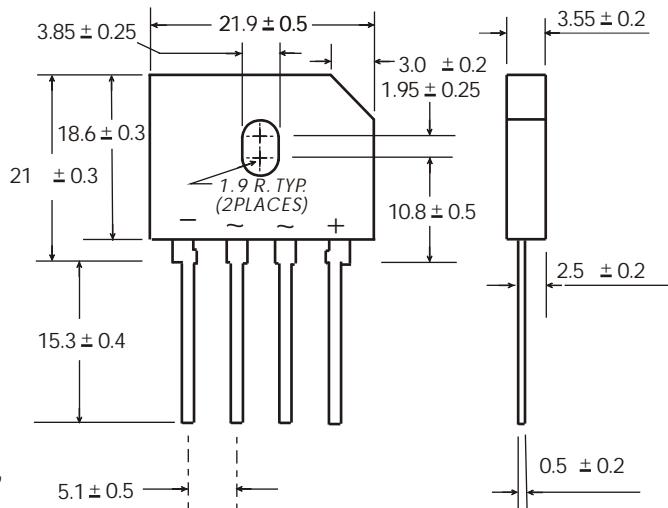
GBU10005 thru GBU1010

10.0 A Single-Phase Silicon Bridge Rectifier Rectifier Reverse Voltage 50 to 1000V



Features 产品特点

- Ideal for P.C. Board mounting 理想的印刷电路板安装方式
- High surge current capability 高浪涌电流能力
- This series is UL listed under the Recognized Component Index, file number E142814
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- High temperature soldering guaranteed 265°C /10 seconds at 5 lbs (2.3kg) tension



Mechanical Data 机械参数

Case: Molded plastic body 外壳: 模压塑料体

Terminals: Plated leads solderable per MIL-STD-202,
Method 208

Polarity: Polarity symbols molded on body 极性: 标记模压于本体

Mounting Position:: Any 安装位置: 任何部位

Mounting Torque: 5 in-lbs max.

Weight: 3.8 grams (approx)

Dimensions in millimeters(1mm = 0.0394") 尺寸以毫米为单位

Maximum Ratings & Thermal Characteristics 最大额定值和热特性

Rating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz.
For Capacitive load derate current by 20%.

Parameter 参数	符号 Symbol	GBU 10005	GBU 1001	GBU 1002	GBU 1004	GBU 1006	GBU 1008	GBU 1010	单位 unit
Maximum repetitive peak reverse voltage 最大中继峰值反向电压	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage 最大直流阻断电压	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current at TA=100°C 最大平均正向整流输出电流(TA=100°C)	IF(AV)				10				A
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM				350				A
Rating for fusing (t<8.3ms)	I ² t				200				A ² sec
Typical thermal resistance per element (1)	ReJA				2.2				°C / W
Operating junction and storage temperature range 存储和工作结温范围	TJ, TSTG				-55 to + 150				°C

Electrical Characteristics 电气特性

Rating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz.
For Capacitive load derate by 20 %.

Parameter 参数	符号 Symbol	GBU 10005	GBU 1001	GBU 1002	GBU 1004	GBU 1006	GBU 1008	GBU 1010	单位 Unit
Maximum instantaneous forward voltage drop per leg at 10.0A 每一引脚最大瞬时正向电压降为10安培	VF				1.05				V
Maximum DC reverse current at rated TA = 25°C DC blocking voltage per element TA = 125°C 每一元件在额定直流阻滞电压下的最大直流反向电流 环境温度为 25摄氏度时	IR				5.0	500			μA

Notes: (1)Thermal resistance from Junction to Ambemton P.C.board mounting.

评级和特性曲线

Rating and Characteristic Curves (TA=25°C Unless otherwise noted)
GBU10005 thru GBU1010

Fig. 1 Derating Curve for Output Rectified Current

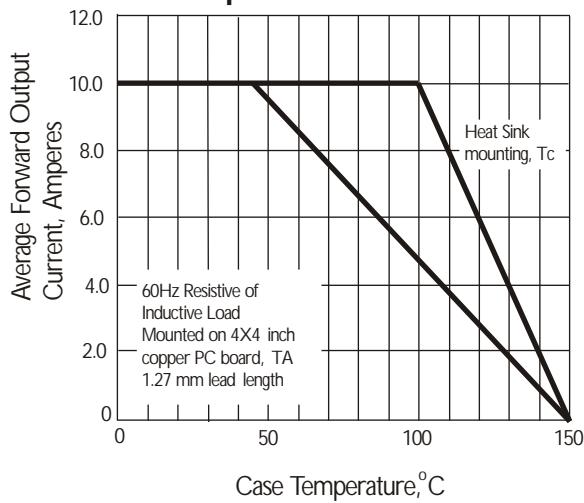


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

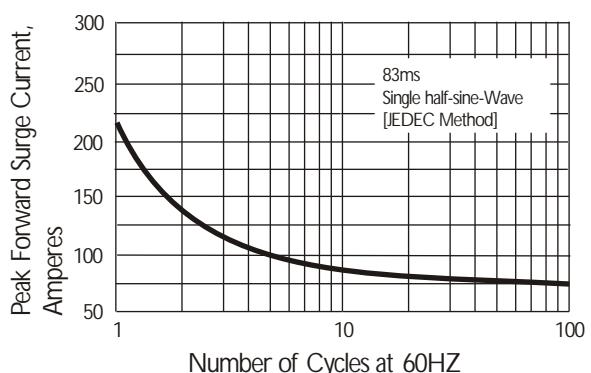


Fig. 3 Typical Instantaneous Forward Characteristics

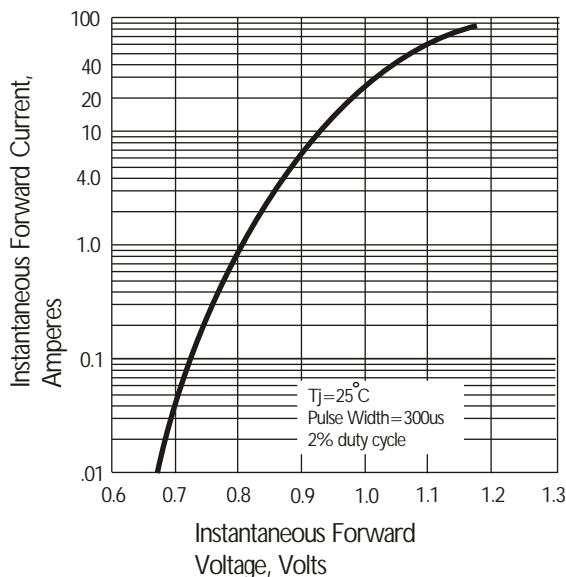


Fig. 4 Typical Reverse Characteristics

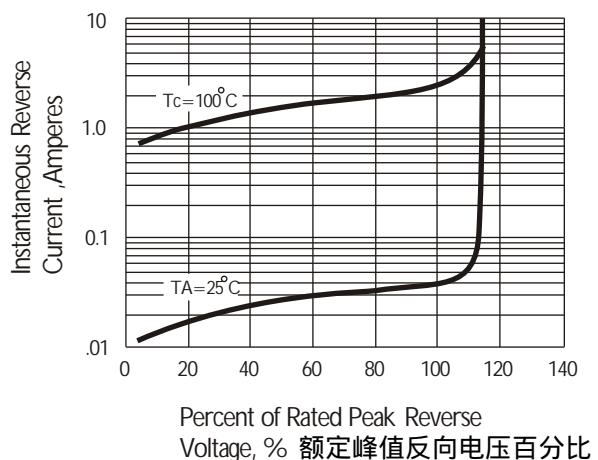
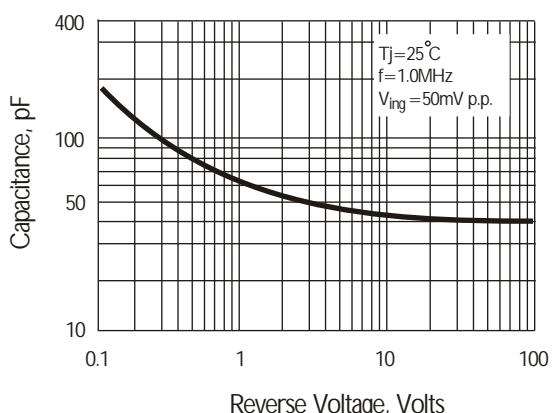


Fig. 5 Typical Junction Capacitance



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